

View Online at <https://aerobasegroup.com/nsn/5961-01-183-6231>

Internal Configuration:

Field effect

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

25.0 gate to source voltage

Current Rating Per Characteristic:

0.50 milliamperes zero-gate-voltage drain current and 5.00 milliamperes zero-gate-voltage drain current

Power Rating Per Characteristic:

400.0 milliwatts total power dissipation

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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